Vishay Semiconductors

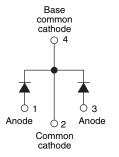
High Performance Schottky Generation 5.0, 2 x 3 A

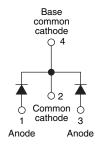






D-PAK (TO-252AA)





VS-6CUT10-E

VS-6CWT10FN-E

PRODUCT SUMMARY					
Package	D-PAK (TO-252AA), I-PAK (TO-251AA)				
I _{F(AV)}	2 x 3 A				
V _R	100 V				
V _F at I _F	0.63 V				
I _{RM} max.	1 mA at 125 °C				
T _J max.	175 °C				
Diode variation	Common cathode				
E _{AS}	12 mJ				

FEATURES





- Very low forward voltage drop
- (e3)
- Extremely low reverse leakage
- Optimized V_F vs. I_R trade off for high efficiency
- RoHS COMPLIANT
- Increased ruggedness for reverse avalanche capability
- RBSOA available
- · Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- · Specific for PV cells bypass diode
- High efficiency SMPS
- High frequency switching
- Output rectification
- Reverse battery protection
- Freewheeling
- DC/DC systems
- Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	. CHARACTERISTICS VALUES UNITS						
V _{RRM}		100	V				
V _F	3 A _{pk} , T _J = 125 °C (typical, per leg)	0.6	V				
T _J	Range	- 55 to 175	°C				

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-6CUT10-E VS-6CWT10FN-E	UNITS
Maximum DC reverse voltage	V_R	T _J = 25 °C	100	V



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ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS	
Maximum average	per leg		50 % duty cycle at T _C = 166 °C, rectangular waveform		3	
forward current	per device	I _{F(AV)}			6	
Maximum peak one cycle non-repetitive surge current per leg		I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	440	Α
			V _{RRM} applied	70		
Non-repetitive avalanche e	nergy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 4 A, L = 1.5 mH		12	mJ
Repetitive avalanche curre	nt per leg	I _{AR}	Limited by frequency of operation and time pulse duration so that $T_J < T_J max$. I_{AS} at $T_J max$. as a function of time pulse. See fig. 8		I _{AS} at T _J max.	Α

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop per leg	V _{FM} ⁽¹⁾	3 A	T _J = 25 °C	0.720	0.79	V
		6 A		0.825	0.91	
		3 A	- T _J = 125 °C	0.60	0.63	
		6 A		0.69	0.74	
Reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	0.3	30	μΑ
		T _J = 125 °C		0.3	1	mA
Junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		114	-	pF
Series inductance per leg	L _S	Measured lead to lead 5 mm from package body		8.0	-	nΗ
Maximum voltage rate of change	dV/dt	Rated V _R		-	10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg	Б	DC encystics	4.7	
Maximum thermal resistance, junction to case per device	- R _{thJC}	DC operation	2.35	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}		0.3	
Approximate weight			0.3	g
			0.01	oz.
Maddan da tar		Case style I-PAK		T10
Marking device		Case style D-PAK	6CWT	10FN

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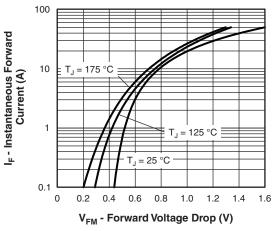


Fig. 1 - Maximum Forward Voltage Drop Characteristics

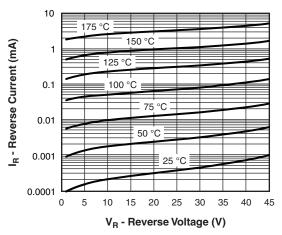


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

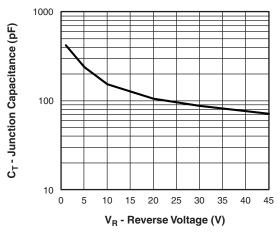


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

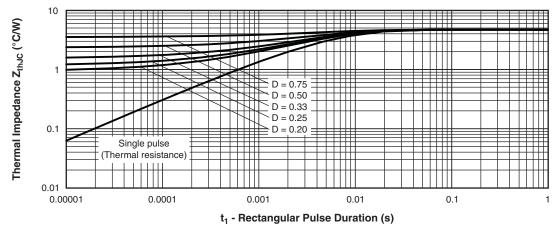


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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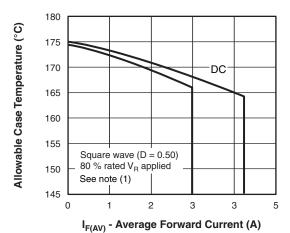


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

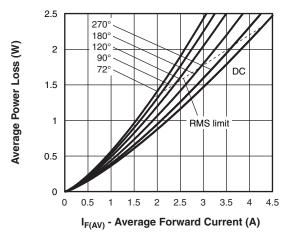
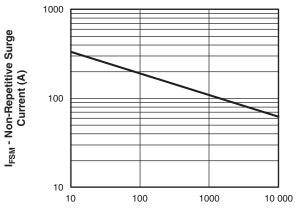


Fig. 6 - Forward Power Loss Characteristics



t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

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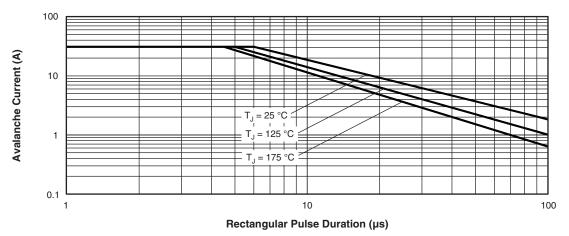


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

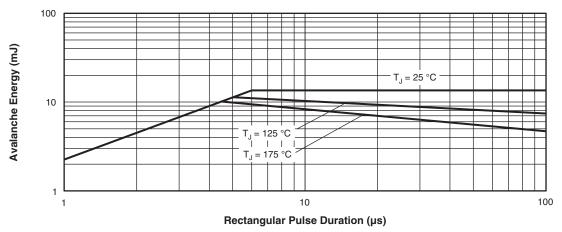
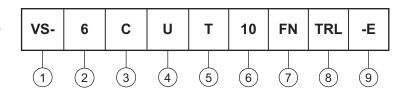


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (2 x 3 A)

3 - Circuit configuration:

C = Common cathode

4 - Package:

U = I-PAK

W = D-PAK

5 - T = Trench

6 - Voltage rating (10 = 100 V)

7 - TO-252AA (D-PAK)

8 - D-PAK, I-PAK:

None = Tube (75 pieces)

D-PAK only:

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

9 - Environmental digit:

-E = RoHS compliant and terminations lead (Pb)-free

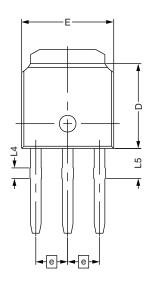
LINKS TO RELATED DOCUMENTS				
Dimonoiono	I-PAK (TO-251AA)	www.vishay.com/doc?95024		
Dimensions	D-PAK (TO-252AA)	www.vishay.com/doc?95448		
Part marking information	I-PAK-E (TO-251AA)	www.vishay.com/doc?95097		
	D-PAK-E (TO-252AA)	www.vishay.com/doc?95176		

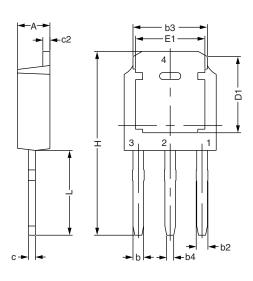


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I-PAK - S

DIMENSIONS FOR I-PAK - S in millimeters





SYMBOL	DIMENSIONAL REQUIREMENTS				
STWIBOL	MIN.	NOM.	MAX.		
E	6.40	6.60	6.70		
L	3.98	4.13	4.28		
L4	0.66	0.76	0.86		
L5	1.96	2.16	2.36		
D	6.00	6.10	6.20		
Н	11.05	11.25	11.45		
b	0.64	0.76	0.88		
b2	0.77	0.84	1.14		
b3	5.21	5.34	5.46		
b4	0.41	0.51	0.61		
е	2.286 BSC				
А	2.20	2.30	2.38		
С	0.40	0.50	0.60		
c2	0.40	0.50	0.60		
D1	5.30		-		
E1	4.40 -		-		



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